

L Number	Hits	Search Text	DB	Time stamp
1	789	349/38	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:12
2	290	349/38 and storage same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
3	79	(349/38 and storage same gate) and second adj insulat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:28
4	6	((349/38 and storage same gate) and second adj insulat\$3) and cmos	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:18
5	26	(349/38 and storage same gate) and second adj insulat\$3 with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
6	194	(349/38 and storage same gate) and (insulat\$3 film) with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:59
7	3	(349/38 and storage same gate) and second adj film with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
8	1500	349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
9	490	349/43 and storage same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
10	52	(349/43 and storage same gate) and second adj (insulat\$3 film) with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:02

L Number	Hits	Search Text	DB	Time stamp
1	789	349/38	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:12
2	290	349/38 and storage same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
3	79	(349/38 and storage same gate) and second adj insulat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:28
4	6	((349/38 and storage same gate) and second adj insulat\$3) and cm0s	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:18
5	26	(349/38 and storage same gate) and second adj insulat\$3 with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
6	194	(349/38 and storage same gate) and (insulat\$3 film) with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 09:59
7	3	(349/38 and storage same gate) and second adj film with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
8	1500	349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
9	490	349/43 and storage same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:01
10	52	(349/43 and storage same gate) and second adj (insulat\$3 film) with pattern\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 10:02
11	2	20020154252.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 12:46
12	1	20020154252.pn. and oxide adj layer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 12:48
13	1	20020154252.pn. and oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06 12:48